

HIGH SPEED 16 BIT CONTENT ADDRESSABLE MEMORY

- Organization – 4 Words x 4 Bits
- Max. Delay of 30 nsec Over 0°C to 75°C Temperature
- Open Collector Outputs – OR Tie Capability
- High Current Sinking Capability – 15 mA max.
- Low Input Load Current – 0.25 mA max.
- DTL & TTL Compatible
- Bit Enable Input – Bit Masking
- Standard 24 Pin Dual In-Line

RAMs

The Intel®3104 is a high speed 16 bit Content Addressable Memory (CAM). It is a linear select 4 word by 4 bit array which is designed to compare data on its inputs with data already stored in its memory and

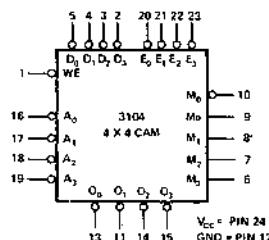
to indicate a match when these data are identical. This equality search is performed on all bits in parallel. The 3104 can also be used as a read/write RAM with linear selection addressing.

PIN CONFIGURATION

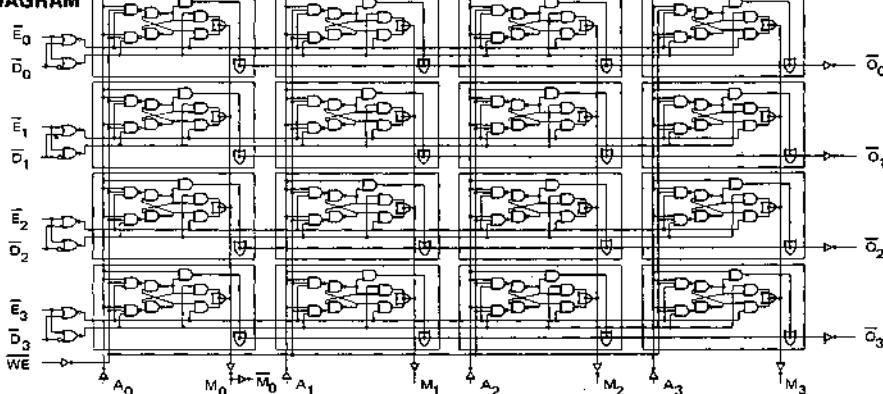
WRITE ENABLE	WE	1	V _{cc}	SUPPLY VOLTAGE
*DATA INPUT	D ₁	2	E ₂	BIT ENABLE INPUT
DATA INPUT	D ₂	3	E ₁	BIT ENABLE INPUT
DATA INPUT	D ₃	4	E ₀	BIT ENABLE INPUT
DATA INPUT	D ₄	5	E ₃	BIT ENABLE INPUT
MATCH OUTPUT	M ₃	6	A ₃	ADDRESS INPUT
MATCH OUTPUT	M ₂	7	A ₂	ADDRESS INPUT
MATCH OUTPUT	M ₁	8	A ₁	ADDRESS INPUT
MATCH OUTPUT	M ₀	9	A ₀	ADDRESS INPUT
MATCH OUTPUT	M̄ ₀	10	̄D ₁	DATA OUTPUT
*DATA OUTPUT	D̄ ₁	11	̄D ₂	DATA OUTPUT
GROUND	GND	12	̄D ₃	DATA OUTPUT
		13		
		14		
		15		
		16		
		17		
		18		
		19		
		20		
		21		
		22		
		23		

*DATA IN and DATA OUT is of the same logic levels. For a chip that is not selected, the data output is at a high level.

LOGIC SYMBOL



LOGIC DIAGRAM



Absolute Maximum Ratings*

Temperature Under Bias	-65°C to +125°C
Storage Temperature	-65°C to +160°C
All Output or Supply Voltages	-0.5 to +7 Volts
All Input Voltages	-1.0 to +5.5 Volts
Output Currents	100 mA

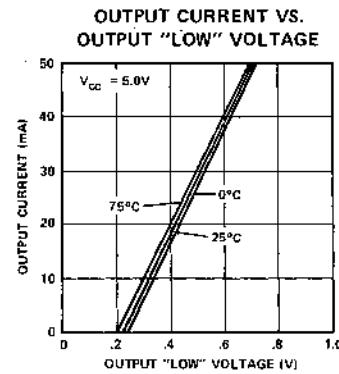
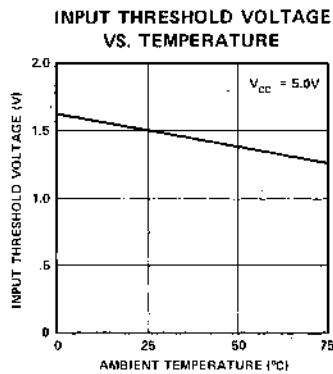
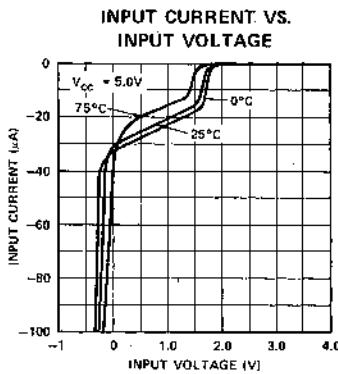
***COMMENT:**

Stresses above those listed under "Absolute Maximum Rating" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or at any other condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

D.C. Characteristics $T_A = 0^\circ\text{C}$ to $+75^\circ\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$; unless otherwise specified.

SYMBOL	PARAMETER	LIMIT			UNIT	TEST CONDITIONS
		MIN.	TYP.	MAX.		
I_{FA}	ADDRESS INPUT LOAD CURRENT			-0.25	mA	$V_{CC} = 5.25\text{V}$ $V_A = .45\text{V}$
I_{FE}	BIT ENABLE INPUT LOAD CURRENT			-0.25	mA	$V_{CC} = 5.25\text{V}$ $V_E = .45\text{V}$
I_{FW}	WRITE ENABLE INPUT LOAD CURRENT			-0.25	mA	$V_{CC} = 5.25\text{V}$ $V_W = .45\text{V}$
I_{FD}	DATA INPUT LOAD CURRENT			-0.25	mA	$V_{CC} = 5.25\text{V}$ $V_D = .45\text{V}$
I_{RA}	ADDRESS INPUT LEAKAGE CURRENT			10	μA	$V_{CC} = 5.25\text{V}$ $V_A = 5.25\text{V}$
I_{RE}	BIT ENABLE INPUT LEAKAGE CURRENT			10	μA	$V_{CC} = 5.25\text{V}$ $V_E = 5.25\text{V}$
I_{RW}	WRITE ENABLE INPUT LEAKAGE CURRENT			10	μA	$V_{CC} = 5.25\text{V}$ $V_W = 5.25\text{V}$
I_{RD}	DATA INPUT LEAKAGE CURRENT			10	μA	$V_{CC} = 5.25\text{V}$ $V_D = 5.25\text{V}$
I_{CEX}	OUTPUT LEAKAGE CURRENT (ALL OUTPUTS)			50	μA	$V_{CC} = 5.25\text{V}$ $V_{CEX} = 5.25\text{V}$
V_{OL}	OUTPUT "LOW" VOLTAGE (ALL OUTPUTS)			0.45	V	$V_{CC} = 4.75\text{V}$ $I_{OL} = 15\text{mA}$
V_{IL}	INPUT "LOW" VOLTAGE (ALL INPUTS)			0.85	V	$V_{CC} = 5\text{V}$
V_{IH}	INPUT "HIGH" VOLTAGE (ALL INPUTS)	2.0			V	$V_{CC} = 5\text{V}$
I_{CC}	POWER SUPPLY CURRENT			125	mA	$V_{CC} = 5.25\text{V}$ OUTPUTS HIGH
C_{IN}^{**}	INPUT CAPACITANCE			5	pF	$V_{IN} = +2.0\text{V}$, $V_{CC} = 0.0\text{V}$ $f = 1\text{ MHz}$
C_{OUT}^{**}	OUTPUT CAPACITANCE			8	pF	$V_{OUT} = +2.0\text{V}$, $V_{CC} = 0.0\text{V}$ $f = 1\text{ MHz}$

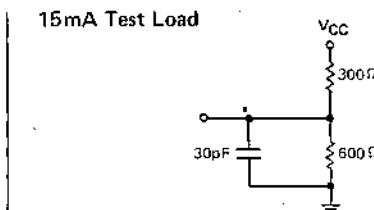
**This parameter is periodically sampled and is not 100% tested.

Typical D.C. Characteristics

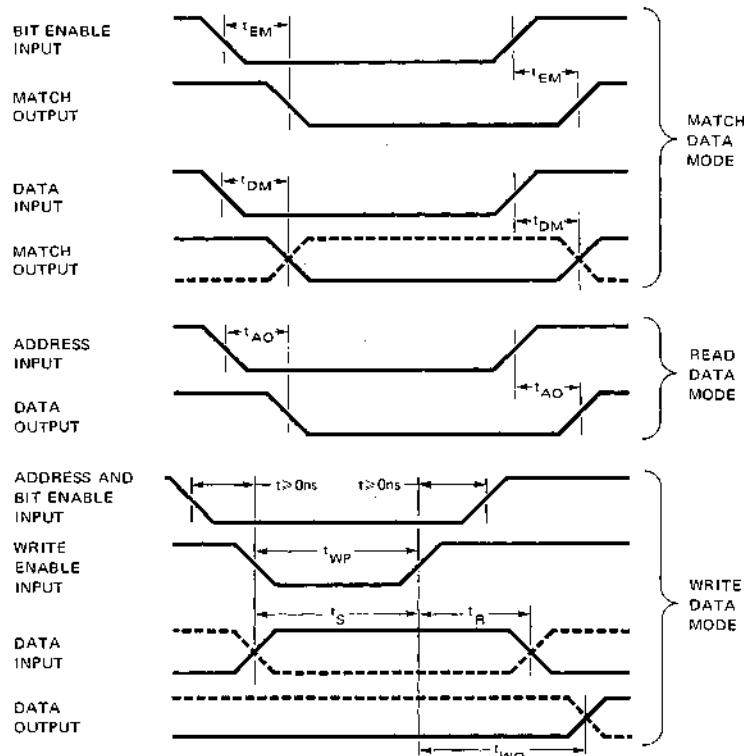
Switching Characteristics

Conditions of Test:

- Input Pulse amplitudes . . 2.5V
- Input pulse rise and fall times of 5 nanoseconds between 1 volt and 2 volts
- Speed measurements are made at 1.5 volt levels
- Output loading is 15 mA and 30 pF



RAMs



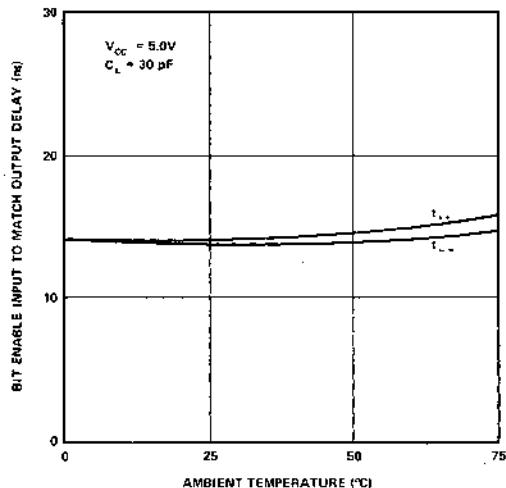
A.C. Characteristics $T_A = 0^\circ\text{C}$ to $+75^\circ\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$; unless otherwise specified.

SYMBOL	PARAMETER	LIMITS			UNIT
		MIN.	Typ. ⁽¹⁾	MAX.	
t_{EM}	BIT ENABLE INPUT TO MATCH OUTPUT DELAY		15	30	ns
t_{DM}	DATA INPUT TO MATCH OUTPUT DELAY		16	30	ns
t_{AO}	ADDRESS INPUT TO OUTPUT DELAY		14	30	ns
t_{WP}	WRITE ENABLE PULSE WIDTH	40	25		ns
t_{WO}	WRITE ENABLE TO OUTPUT DELAY		—	40	ns
t_S	SET-UP TIME ON DATA INPUT		—	40	ns
t_R	RELEASE TIME ON DATA INPUT	0	—		ns

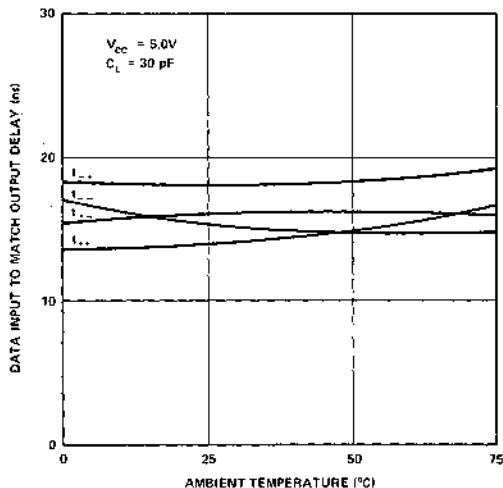
Note 1. Typical values are at nominal voltages and $T_A = 25^\circ\text{C}$.

Typical A.C. Characteristics

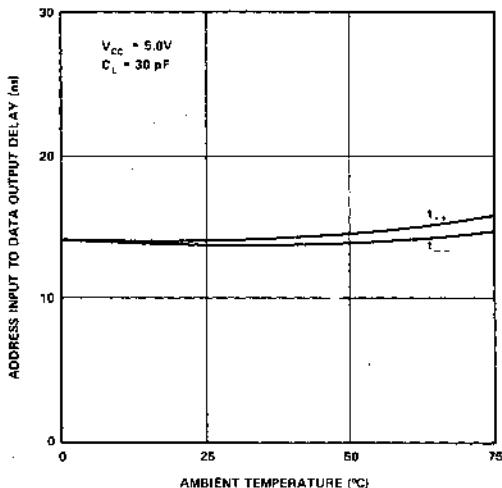
**BIT ENABLE INPUT TO MATCH OUTPUT
DELAY VS. TEMPERATURE**



**DATA INPUT TO MATCH OUTPUT
DELAY VS. TEMPERATURE**



**ADDRESS INPUT TO DATA OUTPUT
DELAY VS. TEMPERATURE**



**WRITE ENABLE PULSE WIDTH
VS. TEMPERATURE**

